

# 2N3970 2N3971 2N3972

**CASE 22-03, STYLE 4  
TO-18 (TO-206AA)**

## JFET SWITCHING

N-CHANNEL — DEPLETION

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	Vdc
Drain-Gate Voltage	V <sub>DG</sub>	40	Vdc
Reverse Gate-Source Voltage	V <sub>GSR</sub>	40	Vdc
Forward Gate Current	I <sub>GF</sub>	50	mAdc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	1.8 10	Watts mW/°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +200	°C

**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted.)**

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Gate-Source Breakdown Voltage (I <sub>G</sub> = 1.0 μAdc, V <sub>GS</sub> = 0)	V <sub>(BR)GSS</sub>	40	—	Vdc
Gate Reverse Current (V <sub>GS</sub> = 20 Vdc, V <sub>DS</sub> = 0)	I <sub>GSS</sub>	—	250	pAdc
Drain Reverse Current (V <sub>DG</sub> = 20 Vdc, I <sub>S</sub> = 0) (V <sub>DG</sub> = 20 Vdc, I <sub>S</sub> = 0, T <sub>A</sub> = 150°C)	I <sub>DGO</sub>	— —	250 500	pAdc nAdc
Drain Cutoff Current (V <sub>DS</sub> = 20 Vdc, V <sub>GS</sub> = -12 Vdc) (V <sub>DS</sub> = 20 Vdc, V <sub>GS</sub> = -12 Vdc, T <sub>A</sub> = 150°C)	I <sub>D(off)</sub>	— —	250 500	pAdc nAdc
Gate Source Voltage (V <sub>DS</sub> = 20 Vdc, I <sub>D</sub> = 1.0 nAdc)	V <sub>GS</sub>	4.0 2.0 0.5	10 5.0 3.0	Vdc

### **ON CHARACTERISTICS**

Zero-Gate-Voltage Drain Current(1) (V <sub>DS</sub> = 20 Vdc, V <sub>GS</sub> = 0)	2N3970 2N3971 2N3972	I <sub>DSS</sub>	50 25 5.0	150 75 30	mAdc
Drain-Source On-Voltage (I <sub>D</sub> = 20 mA, V <sub>GS</sub> = 0) (I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0) (I <sub>D</sub> = 5.0 mA, V <sub>GS</sub> = 0)	2N3970 2N3971 2N3972	V <sub>DS(on)</sub>	— — —	1.0 1.5 2.0	Vdc
Static Drain-Source On Resistance (I <sub>D</sub> = 1.0 mA, V <sub>GS</sub> = 0)	2N3970 2N3971 2N3972	r <sub>DS(on)</sub>	— — —	30 60 100	Ohms

### **SMALL-SIGNAL CHARACTERISTICS**

Drain-Source "ON" Resistance (V <sub>GS</sub> = 0, I <sub>D</sub> = 0, f = 1.0 kHz)	2N3970 2N3971 2N3972	r <sub>ds(on)</sub>	— — —	30 60 100	Ohms
Input Capacitance (V <sub>DS</sub> = 20 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)	C <sub>iss</sub>	—	—	25	pF
Reverse Transfer Capacitance (V <sub>DS</sub> = 0, V <sub>GS</sub> = -12 Vdc, f = 1.0 MHz)	C <sub>rss</sub>	—	—	6.0	pF

### **SWITCHING CHARACTERISTICS**

Turn-On Delay Time	Test Condition for 2N3970: (V <sub>DD</sub> = 10 Vdc, V <sub>GS(on)</sub> = 0, I <sub>D(on)</sub> = 20 mA, V <sub>GS(off)</sub> = 10 Vdc)	2N3970 2N3971 2N3972	t <sub>d(on)</sub>	— — —	10 15 40	ns
	t <sub>r</sub>		— — —	10 15 40	ns	
	t <sub>off</sub>		— — —	30 60 100	ns	
Rise Time	Test Condition for 2N3971: (V <sub>DD</sub> = 10 Vdc, V <sub>GS(on)</sub> = 0, I <sub>D(on)</sub> = 10 mA, V <sub>GS(on)</sub> = 5.0 Vdc)	2N3970 2N3971 2N3972				
Turn-Off Time	Test Condition for 2N3972: (V <sub>DD</sub> = 10 Vdc, V <sub>GS(on)</sub> = 0, I <sub>D(on)</sub> = 5.0 mA, V <sub>GS(off)</sub> = 3.0 Vdc)	2N3970 2N3971 2N3972				

(1) Pulse Test: Pulse Width = 300 μs, Duty Cycle = 3.0%.